General Description

The MAX9777/MAX9778 combine a stereo 3W bridgetied load (BTL) audio power amplifier, stereo singleended (SE) headphone amplifier, headphone sensing, and a 2:1 input multiplexer all in a tiny 28-pin thin QFN package. These devices operate from a single 4.5V to 5.5V supply and feature an industry-leading 100dB PSRR, allowing these devices to operate from noisy supplies without the addition of a linear regulator. An ultra-low 0.002% THD+N ensures clean, low-distortion amplification of the audio signal. Patented click-andpop suppression minimizes audible transients on power and shutdown cycles. Power-saving features include low 4mV Vos (minimizes DC current drain through the speakers), low 13mA supply current, and a 10µA shutdown mode. A MUTE function allows the outputs to be quickly enabled or disabled.

A headphone sense input detects the presence of a headphone jack and automatically configures the amplifiers for either speaker or headphone mode. In speaker mode, the amplifiers can deliver up to 3W of continuous average power into a 3Ω load. In headphone mode, the amplifier can deliver up to 200mW of continuous average power into a 16Ω load. The gain of the amplifiers is externally set, allowing maximum flexibility in optimizing output levels for a given load. The amplifiers also feature a 2:1 input multiplexer, allowing multiple audio sources to be selected. The multiplexer can also be used to compensate for limitations in the frequency response of the loud speakers by selecting an external equalizer network. The various functions are controlled by either an I²C[†]-compatible (MAX9777) or simple parallel control interface (MAX9778).

The MAX9777/MAX9778 are available in a thermally efficient 28-pin thin QFN package (5mm x 5mm x 0.8mm). These devices have thermal-overload protection (OVP) and are specified over the extended -40° C to $+85^{\circ}$ C temperature range.

Applications

Notebooks	PC Audio Peripherals
Portable DVD Players	Camcorders
Tablet PCs	Multimedia Monitor

[†]Purchase of I²C components from Maxim Integrated Products, Inc., or one of its sublicensed Associate Companies, conveys a license under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification defined by Philips.

///XI//

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

_Features

- Industry-Leading, Ultra-High 100dB PSRR
- PC99/01 Compliant
- ♦ 3W BTL Stereo Speaker Amplifier
- ♦ 200mW Stereo Headphone Amplifier
- Low 0.002% THD+N
- Patented Click-and-Pop Suppression
- ESD-Protected Outputs
- Low Quiescent Current: 13mA
- ♦ Low-Power Shutdown Mode: 10µA
- ♦ MUTE Function
- ♦ Headphone Sense Input
- Stereo 2:1 Input Multiplexer
- Optional 2-Wire, I²C-Compatible or Parallel Interface
- Tiny 28-Pin Thin QFN (5mm x 5mm x 0.8mm) Package

PART	CONTROL INTERFACE	PIN- PACKAGE	PKG CODE
MAX9777ETI+	I ² C Compatible	28 Thin QFN-EP*	T2855-6
MAX9778ETI+	Parallel	28 Thin QFN-EP*	T2855-6

Note: All devices are specified over the -40°C to +85°C operating temperature range.

+Denotes lead-free package.

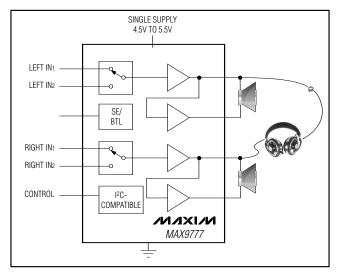
*EP = Exposed paddle.

Pin Configurations and Functional Diagrams appear at end of data sheet.

_Simplified Block Diagram

Maxim Integrated Products 1

Ordering Information



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MAX9777/MAX9778

ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND	+6V
PV _{DD} to V _{DD}	
PGND to GND	±0.3V
All Other Pins to GND	0.3V to (V _{DD} + 0.3V)
Continuous Input Current (into any pin ex	cept power-supply
and output pins)	±20mA
OUT Short Circuit to GND, VDD	10s
Short Circuit Between OUT_+ and OUT_	Continuous

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
28-Pin TQFN, Multilayer Board	
(derate 34.5mW/°C above +70°C)	2758.6mW
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{DD} = PV_{DD} = 5.0V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1\mu F, R_{IN} = R_F = 15k\Omega, R_L = \infty$. TA = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	cc	NDITION	NS	MIN	ТҮР	MAX	UNITS
Supply Voltage Range	V _{DD} /PV _{DD}	Inferred from PSRF	R test		4.5		5.5	V
Quiescent Supply Current		BTL mode, HPS =	OV, MAX	9777/MAX9778		13	32	
(IVDD + IPVDD)	IDD	Single-ended mode	e, HPS =	V _{DD}		7	18	mA
Shutdown Current	ISHDN	SHDN = GND				10	50	μA
Switching Time	tsw	Gain or input switc	hing			10		μs
Turn-On Time	tou	$C_{BIAS} = 1 \mu F$				300		
Tum-On Time	ton	$C_{BIAS} = 0.1 \mu F$				30		ms
Thermal Shutdown Threshold						+160		°C
Thermal Shutdown Hysteresis						15		°C
OUTPUT AMPLIFIERS (SPEAKE	R MODE, H	PS = GND)						
Output Offset Voltage	Vos	OUT_+ - OUT, Av	v = 1V/V			±4	±32	mV
		$V_{DD} = 4.5V$ to 5.5V	1		75	100		
Power-Supply Rejection Ratio (Note 2)	PSRR	f = 1kHz, VRIPPLE =	= 200mV _F	p_p		82		dB
		$f = 20kHz, V_{RIPPLE}$	= 200m	∕P-P		70		
		f _{IN} = 1kHz,	$R_L = 8$	Ω		1.4		
Output Power	Pout	THD+N < 1%,	$R_L = 4$	Ω		2.6		W
		$T_A = +25^{\circ}C$	$R_L = 3$	Ω		3		
Total Harmonic Distortion Plus	THD+N	$f_{IN} = 1 kHz, BW =$	Pout =	= 1W, $R_L = 8\Omega$		0.005		~ %
Noise	IIID+N	22Hz to 22kHz	Pout =	= 2W, R_{L} = 4 Ω		0.01		/0
Signal-to-Noise Ratio	SNR	$R_L = 8\Omega$, $P_{OUT} = 1$	W, BW =	22Hz to 22kHz		95		dB
Slew Rate	SR					1.6		V/µs
Maximum Capacitive Load Drive	CL	No sustained oscill	ations			1		nF
Crosstalk		$f_{IN} = 10 kHz$				73		dB
Click/Pop Level	Кср	Peak voltage, A-we 32 samples per see	•	Into shutdown		-50		dBV
		(Notes 2, 6)		Out of shutdown		-65		



ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = PV_{DD} = 5.0V, GND = PGND = 0V, V_{\overline{SHDN}} = 5V, C_{BIAS} = 1\mu F, R_{IN} = R_F = 15k\Omega, R_L = \infty$. T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS			MIN	ТҮР	MAX	UNITS
OUTPUT AMPLIFIERS (HEADPH	IONE MODE	, HPS = V _{DD})						
		$V_{DD} = 4.5V$ to 5.5V			75	106		
Power-Supply Rejection Ratio (Note 2)	PSRR	$f = 1 kHz, V_{RIPPLE} = 20$	00mV _F	P-P		88		dB
		$f = 20kHz, V_{RIPPLE} = 2$	200m\	/P-P		76		
Output Power	Роит	$f_{IN} = 1 kHz, THD+N <$	RL =	32Ω		88		mW
	FOUI	1%, T _A = +25°C	RL =	16Ω		200		11100
Total Harmonic Distortion Plus	THD+N	f _{IN} = 1kHz,	00	T = 60 mW, $= 32 \Omega$		0.002		
Noise	IHD+N	BW = 22Hz to 22kHz		T = 125mW, 16Ω		0.002		%
Signal-to-Noise Ratio	SNR	$R_L = 32\Omega$, BW = 22Hz V _{OUT} = 1V _{RMS}	to 22	kHz,		92		dB
Slew Rate	SR					1.8		V/µs
Maximum Capacitive Load Drive	CL	No sustained oscillation	ons			2		nF
Crosstalk		f _{IN} = 10kHz				78		dB
BIAS VOLTAGE (BIAS)								
BIAS Voltage	VBIAS				2.35	2.5	2.65	V
Output Resistance	R _{BIAS}					50		kΩ
DIGITAL INPUTS (MUTE, SHDN,	HPS_EN, G	AINA/B, IN1/2)						
Input-Voltage High	VIH				2			V
Input-Voltage Low	VIL						0.8	V
Input Leakage Current	lin						±1	μA
HEADPHONE SENSE INPUT (HF	PS)							-
Input-Voltage High	VIH				0.9 x V _{DD}			V
Input-Voltage Low	VIL						0.7 x V _{DD}	V
Input Leakage Current	l _{IN}			•			±1	μA
Click/Pop Level	Кср	Peak voltage, A-weigh 32 samples per secon		Into shutdown		-70		dBV
	01	(Notes 2, 4)		Out of shutdown		-52		

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = PV_{DD} = 5.0V, GND = PGND = 0V, V_{\overline{SHDN}} = 5V, C_{BIAS} = 1\mu F, R_{IN} = R_F = 15k\Omega, R_L = \infty$. T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
2-WIRE SERIAL INTERFACE (S	CL, SDA, AD	D, INT) (MAX9777)				•
Input-Voltage High	VIH		2.6			V
Input-Voltage Low	VIL				0.8	V
Input Hysteresis				0.2		V
Input High Leakage Current	Iн	$V_{IN} = 5V$			±1	μA
Input Low Leakage Current	١ _١ ٢	$V_{IN} = 0V$			±1	μΑ
Input Capacitance	CIN			10		pF
Output-Voltage Low	VOL	I _{OL} = 3mA			0.4	V
Output Current High	IOH	$V_{OH} = 5V$			1	μA
TIMING CHARACTERISTICS (M	IAX9777)					
Serial Clock Frequency	fscl				400	kHz
Bus Free Time Between STOP and START Conditions	tBUF		1.3			μs
START Condition Hold Time	thd:sta		0.6			μs
START Condition Setup Time	tsu:sta		0.6			μs
Clock Period Low	tLOW		1.3			μs
Clock Period High	thigh		0.6			μs
Data Setup Time	tsu:dat		100			ns
Data Hold Time	thd:dat	(Note 3)	0		0.9	μs
Receive SCL/SDA Rise Time	tr	(Note 4)	20 + 0.1C _B		300	ns
Receive SCL/SDA Fall Time	tf	(Note 4)	20 + 0.1C _B		300	ns
Transmit SDA Fall Time	tf	(Note 4)	20 + 0.1C _B		250	ns
Pulse Width of Suppressed Spike	tSP	(Note 5)		50		ns

Note 1: All devices are 100% production tested at +25°C. All temperature limits are guaranteed by design.

Note 2: Inputs AC-coupled to GND.

Note 3: A master device must provide a hold time of at least 300ns for the SDA signal to bridge the undefined region of SCL's falling edge.

Note 4: C_B = total capacitance of one of the bus lines in picofarads. Device tested with C_B = 400pF. 1k Ω pullup resistors connected from SDA/SCL to V_{DD}.

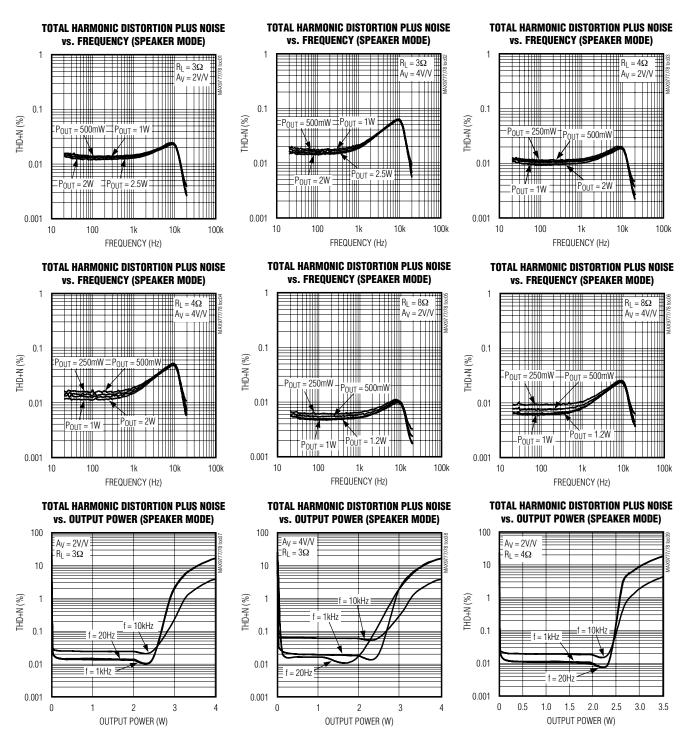
Note 5: Input filters on SDA, SCL, and ADD suppress noise spikes of less than 50ns.

Note 6: Headphone mode testing performed with 32Ω resistive load connected to GND. Speaker mode testing performed with 8Ω resistive load connected to GND. Mode transitions are controlled by SHDN. KCP level is calculated as 20log[(peak voltage during mode transition, no input signal)/1V_{RMS}]. Units are expressed in dBV.

/N/IXI/N

_Typical Operating Characteristics

 $(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$



M /X / M



Typical Operating Characteristics (continued)

 $(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$

TOTAL HARMONIC DISTORTION PLUS NOISE TOTAL HARMONIC DISTORTION PLUS NOISE TOTAL HARMONIC DISTORTION PLUS NOISE vs. OUTPUT POWER (SPEAKER MODE) vs. OUTPUT POWER (SPEAKER MODE) vs. OUTPUT POWER (SPEAKER MODE) 100 100 100 $A_V = 4V/V$ $A_V = 2V/V$ $A_V = 4V/V$ $R_L = 4\Omega$ $R_L = 8\Omega$ $R_1 = 8\Omega$ 10 10 10 = 10kHz THD+N (%) 1 THD+N (%) 1 THD+N (%) 1 f = 10kHz f = 1 kHzf = 10 kHz0.1 0.1 0.1 f = 1 kHz= 1kHz 0.01 0.01 0.01 f = 20Hz f = 20Hz = 20Hz 0.001 0.001 0.001 0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 0 0.5 1.0 1.5 2.0 0 0.5 1.0 1.5 2.0 OUTPUT POWER (W) OUTPUT POWER (W) OUTPUT POWER (W) **OUTPUT POWER vs. AMBIENT TEMPERATURE OUTPUT POWER vs. AMBIENT TEMPERATURE OUTPUT POWER vs. AMBIENT TEMPERATURE** (SPEAKER MODE) (SPEAKER MODE) (SPEAKER MODE) 4 4 2.0 THD+N = 10%THD+N = 10%THD+N = 10%3 3 1.5 OUTPUT POWER (W) OUTPUT POWER (W) OUTPUT POWER (W) $THD+\dot{N} = 1\%$ THD+N = 1% THD+N = 1%2 2 1.0 1 1 0.5 f = 1kHz f = 1 kHzf = 1kHz $R_L = 8\Omega$ $R_L = 3\Omega$ $R_L = 4\Omega$ 0 0 0 -15 -40 -15 10 35 60 85 -15 10 35 60 -40 10 35 60 85 -40 85 AMBIENT TEMPERATURE (°C) AMBIENT TEMPERATURE (°C) AMBIENT TEMPERATURE (°C) **OUTPUT POWER vs. LOAD RESISTANCE POWER DISSIPATION vs. OUTPUT POWER** (SPEAKER MODE) (SPEAKER MODE) 1.6 5 f = 1kHz 1.4 4 1.2 POWER DISSIPATION (W) OUTPUT POWER (W) 1.0 3 0.8 THD+N 2 0.6 0.4 1 02 $R_I = 4\Omega$ f = 1kHz

0 L

0.5

1.5

1.0

OUTPUT POWER (W)

2.5

2.0

0

10

100

LOAD RESISTANCE (Ω)

1k

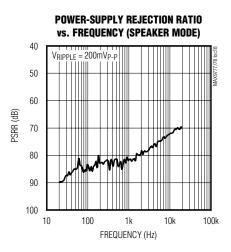
10k

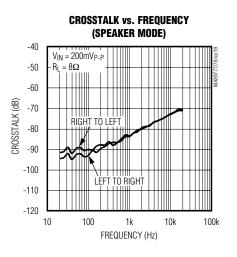
100k

MAX9777/MAX9778

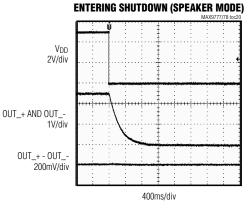
Typical Operating Characteristics (continued)

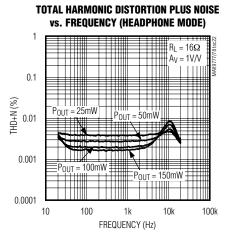
 $(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$





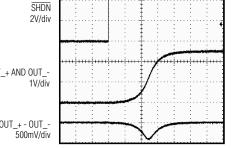
EXITING SHUTDOWN (SPEAKER MODE) SHDN 2V/div OUT_+ AND OUT_-1V/div OUT + - OUT -500mV/div









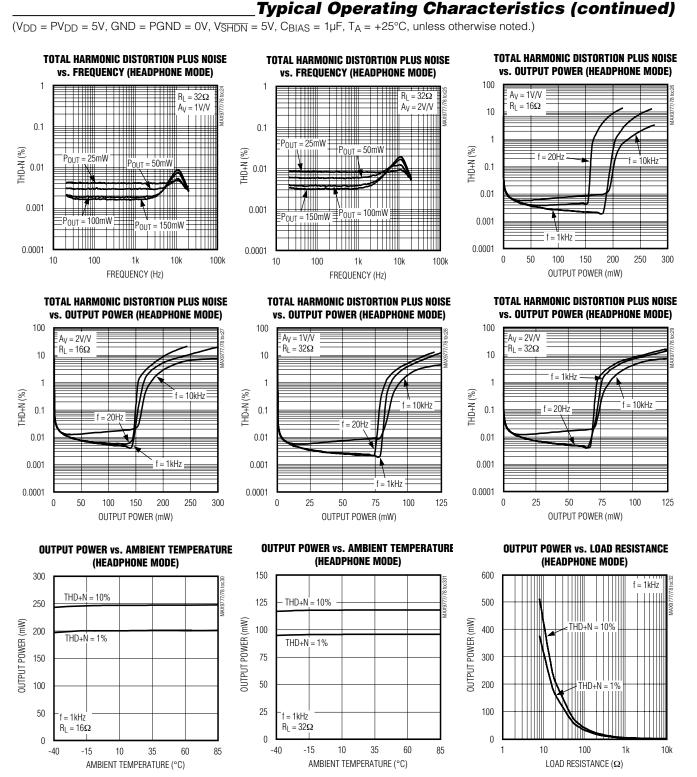


100ms/div

TOTAL HARMONIC DISTORTION PLUS NOISE vs. FREQUENCY (HEADPHONE MODE) 1 #RL = 16Ω $A_V = 2V/V$ 0.1 $P_{OUT} = 25 \text{mW}$: 50mW THD+N (%) 0.01 0.001 POUT = 100mW Н Роит 150mW +++ 0.0001 10 100 1k 100k 10k FREQUENCY (Hz)

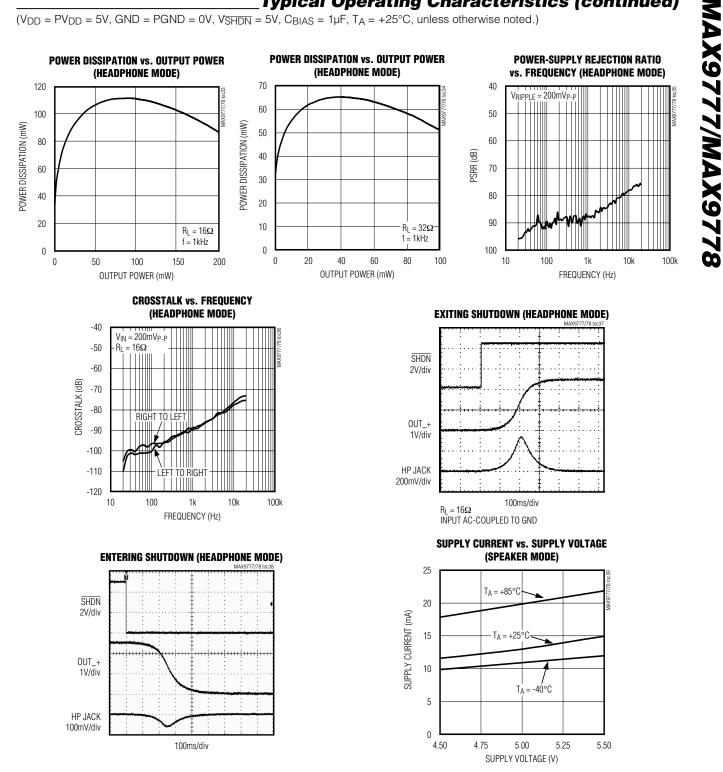
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MAX9777/MAX9778



Typical Operating Characteristics (continued)

 $(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{\overline{SHDN}} = 5V, C_{BIAS} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$

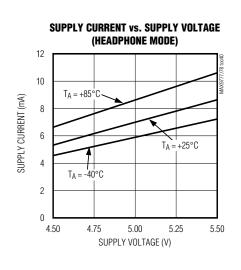


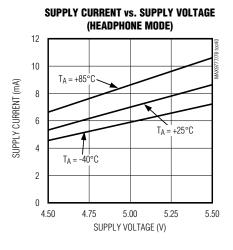
MIXIM

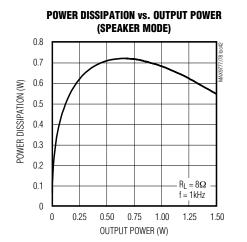
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Typical Operating Characteristics (continued)

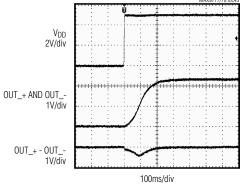
 $(V_{DD} = PV_{DD} = 5V, GND = PGND = 0V, V_{SHDN} = 5V, C_{BIAS} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$













Pin Description

PII	N		FUNCTION
MAX9777	MAX9778	NAME	FUNCTION
1		SDA	Serial Data I/O
2		ĪNT	Interrupt Output
3, 4	3, 4	V _{DD}	Power-Supply Input
5	5	INL1	Left-Channel Input 1
6	6	INL2	Left-Channel Input 2
7	7	GAINLA	Left-Channel Gain Set A
8	8	GAINLB	Left-Channel Gain Set B
9, 13, 23, 27	9, 13, 23, 27	PGND	Power Ground. Connect to GND.
10	10	OUTL+	Left-Channel Bridged Amplifier Positive Output. OUTL+ also serves as the left-channel headphone amplifier output.
11, 25	11, 25	PV _{DD}	Output Amplifier Power Supply
12	12	OUTL-	Left-Channel Bridged Amplifier Negative Output
14	14	SHDN	Active-Low Shutdown Input. Connect SHDN to VDD for normal operation.
15	_	ADD	Address Select. A logic-high sets the address LSB to 1, a logic-low sets the address LSB to zero.
16	16	HPS	Headphone Sense Input. A logic-high configures the device as a single- ended headphone amp. A logic-low configures the device as a BTL speaker amp.
17	17	BIAS	DC Bias Bypass Terminal. See the BIAS Capacitor section for capacitor selection. Connect C_{BIAS} from BIAS to GND.
18	18	GND	Ground. Connect to PGND.
19	19	INR1	Right-Channel Input 1
20	20	INR2	Right-Channel Input 2
21	21	GAINRA	Right-Channel Gain Set A
22	22	GAINRB	Right-Channel Gain Set B
24	24	OUTR+	Right-Channel Bridged Amplifier Positive Output. OUTR+ also serves as the right-channel headphone amplifier output.
26	26	OUTR-	Right-Channel Bridged Amplifier Negative Output
28		SCL	Serial Clock Line
_	1	MUTE	Active-High Mute Input
	2	HPS_EN	Headphone Enable. A logic-high enables HPS. A logic-low disables HPS and the device is always configured as a BTL speaker amplifier.
	15	GAINĀ/B	Gain Select. A logic-low selects the gain set by GAIN_A. A logic-high selects the gain set by GAIN_B.
_	28	IN1/2	Input Select. A logic-low selects amplifier input 1. A logic-high selects amplifier input 2.
EP	EP	EP	Exposed Paddle. Connect to GND.

MAX9777/MAX9778

Detailed Description

The MAX9777/MAX9778 feature 3W BTL speaker amplifiers, 200mW headphone amplifiers, input multiplexers, headphone sensing, and comprehensive clickand-pop suppression. The MAX9777/MAX9778 are stereo BTL/headphone amplifiers. The MAX9777 is controlled through an I²C-compatible, 2-wire serial interface. The MAX9778 is controlled through five logic inputs: MUTE, SHDN, HPS_EN, GAINA/B, and IN1/2 (see the *Selector Guide*). The MAX9777/MAX97778 feature exceptional PSRR (100dB at 1kHz), allowing these devices to operate from noisy digital supplies without the need for a linear regulator.

The speaker amplifiers use a BTL configuration. The signal path is composed of an input amplifier and an output amplifier. Resistor R_{IN} sets the input amplifier's gain, and resistor R_{F} sets the output amplifier's gain. The output of these two amplifiers serves as the input to a slave amplifier configured as an inverting unity-gain follower. This results in two outputs, identical in magnitude, but 180° out of phase. The overall gain of the speaker amplifiers is twice the product of the two amplifier gains (see the *Gain-Setting Resistors* section). A feature of this architecture is that there is no phase inversion from input to output.

When configured as a headphone (single-ended) amplifier, the slave amplifier is disabled, muting the speaker and the main amplifier drives the headphone. The MAX9777/MAX9778 can deliver 3W of continuous power into a 3 Ω load with less than 1% THD+N in speaker mode, and 200mW of continuous average power into a 16 Ω load with less than 1% THD+N in headphone mode. These devices also feature thermal-overload protection.

BIAS

These devices operate from a single 5V supply, and feature an internally generated, power-supply independent, common-mode bias voltage of 2.5V referenced to GND. BIAS provides both click-and-pop suppression and sets the DC bias level for the audio outputs. BIAS is internally connected to the noninverting input of each speaker amplifier (see the *Typical Application Circuits* and *Functional Diagrams*). Choose the value of the bypass capacitor as described in the *BIAS Capacitor* section. No external load should be applied to BIAS. Any load lowers the BIAS voltage, affecting the overall performance of the device.

Input Multiplexer

Each amplifier features a 2:1 input multiplexer, allowing input selection between two stereo sources. Both multiplexers are controlled by bit 1 in the control register (MAX9777) or by the IN1/2 pin (MAX9778). A logic-low selects input IN_1 and a logic-high selects input IN_2.

The input multiplexer can also be used to further expand the number of gain options available from the MAX9777/MAX9778 family. Connecting the audio source to the device through two different input resistors (Figure 1) increases the number of gain options from two to four. Additionally, the input multiplexer allows a speaker equalization network to be switched into the speaker signal path. This is typically useful in optimizing acoustic response from speakers with small physical dimensions.

Headphone Sense Enable

The HPS input is enabled by HPS_EN (MAX9778) or the HPS_D bit (MAX9777). HPS_D or HPS_EN determines whether the device is in automatic detection mode or fixed-mode operation (see Tables 1a and 1b).

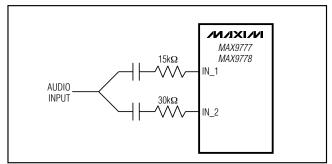


Figure 1. Using the Input Multiplexer for Gain Setting

Table 1a. MAX9777 HPS Setting

	INPUTS			0.4.11
HPS_D BIT	HPS	SPKR/HP BIT	MODE	GAIN PATH*
0	0	Х	BTL	А
0	1	Х	SE	В
1	Х	0	BTL	A or B
1	Х	1	SE	A or B

*Note:

A—GAINA path selected

B—GAINB path selected

A or B—Gain path selected by GAINAB control bit in register 02h



INP	UTS	MODE	GAIN PATH*
HPS_EN	HPS	WODE	GAIN PATH
0	Х	BTL	A or B
1	0	BTL	A or B
1	1	SE	A or B

Table 1b. MAX9778 HPS Setting

*Note:

A or B—Gain path selected by external GAINAB

Headphone Sense Input (HPS)

With headphone sense enabled, a voltage on HPS less than $0.7 \times V_{DD}$ sets the device to speaker mode. A voltage greater than $0.9 \times V_{DD}$ disables the inverting bridge amplifier (OUT_-), which mutes the speaker amplifier and sets the device into headphone mode.

For automatic headphone detection, enable headphone sense and connect HPS to the control pin of a 3-wire headphone jack as shown in Figure 2. With no headphone present, the resistive voltage-divider created by R1 and R2 sets the voltage on HPS to be less than 0.7 x V_{DD}, setting the device to speaker mode and the gain setting defaults to GAINA (MAX9777). When a headphone plug is inserted into the jack, the control pin is disconnected from the tip contact, and HPS is pulled to V_{DD} through R1, setting the device into headphone mode and the gain-setting defaults to GAINB (MAX9777) (see the *Gain Select* section). Place a resistor in series with the control pin and HPS (R3) to prevent any audio signal from coupling into HPS when the device is in speaker mode.

The MAX9777/MAX9778 feature a 10μ A, low-power shutdown mode that reduces quiescent current consumption and extends battery life. The drive amplifiers and bias circuitry are disabled, the amplifier outputs (OUT_) go high impedance, and BIAS is driven to GND. Driving SHDN low places the devices into shutdown mode, disables the interface, and resets the l²C registers to a default state. A logic-high on SHDN enables the devices.

MAX9777 Software Shutdown

Shutdown

A logic-high on bit 0 of the SHDN register places the MAX9777 in shutdown mode. A logic-low enables the

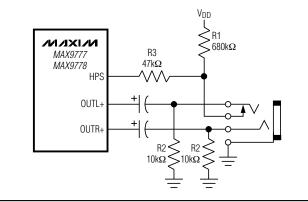


Figure 2. HPS Configuration Circuit

device. The digital section of the MAX9777 remains active when the device is shut down through the interface. All devices feature a logic-low on the SHDN input.

MUTE

The MAX9777/MAX9778 feature a mute mode. When the device is muted, the input is disconnected from the amplifiers. MUTE does not shut down the device.

MAX9777 MUTE

The MAX9777 MUTE mode is selected by writing to the MUTE register (see the *Mute Register* section). The left and right channels can be independently muted.

MAX9778 MUTE

The MAX9778 features an active-high MUTE input that mutes all channels.

Click-and-Pop Suppression

The MAX9777/MAX9778 feature Maxim's patented comprehensive click-and-pop suppression. When entering or exiting shutdown, the common-mode bias voltage of the amplifiers is slowly ramped to and from the DC bias point using an S-shaped waveform. In headphone mode, this waveform shapes the frequency spectrum, minimizing the amount of audible components present at the headphone. In speaker mode, the BTL amplifiers start up in the same fashion as in headphone mode. When entering shutdown, both amplifier outputs ramp to GND quickly and simultaneously. To maximize clickand-pop suppression, drive SHDN to 0V before powerup or power-down transitions.

Digital Interface

The MAX9777 features an I²C/SMBus[™]-compatible 2wire serial interface consisting of a serial data line (SDA) and a serial clock line (SCL). SDA and SCL facilitate bidirectional communication between the MAX9777 and the master at clock rates up to 400kHz. Figure 3 shows the 2-wire interface timing diagram. The MAX9777 is a transmit/receive slave-only device, relying upon a master to generate a clock signal. The master (typically a microcontroller) initiates data transfer on the bus and generates SCL to permit that transfer.

A master device communicates to the MAX9777 by transmitting the proper address followed by a command and/or data words. Each transmit sequence is framed by a START (S) or REPEATED START (Sr) condition and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge clock pulse.

SDA and SCL are open-drain outputs requiring a pullup resistor (500Ω or greater) to generate a logic-high voltage. Series resistors in line with SDA and SCL are optional. These series resistors protect the input stages of the

SMBus is a trademark of Intel Corp.

devices from high-voltage spikes on the bus lines, and minimize crosstalk and undershoot of the bus signals.

Bit Transfer

One data bit is transferred during each SCL clock cycle. The data on SDA must remain stable during the high period of the SCL clock pulse. Changes in SDA while SCL is high are control signals (see the *START* and *STOP* Conditions section). SDA and SCL idle high when the I²C bus is not busy.

START and STOP Conditions

When the serial interface is inactive, SDA and SCL idle high. A master device initiates communication by issuing a START condition. A START condition is a high-tolow transition on SDA with SCL high. A STOP condition is a low-to-high transition on SDA while SCL is high (Figure 4). A START condition from the master signals the beginning of a transmission to the MAX9777. The master terminates transmission by issuing the STOP condition; this frees the bus. If a REPEATED START condition is generated instead of a STOP condition, the bus remains active.

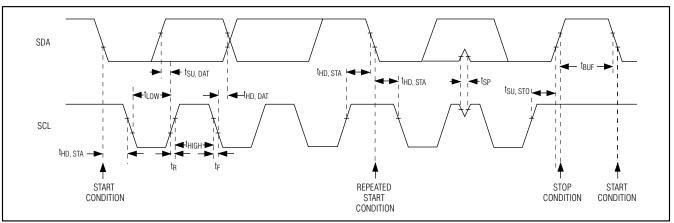


Figure 3. 2-Wire Serial-Interface Timing Diagram

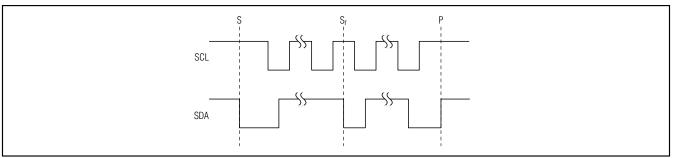


Figure 4. START/STOP Conditions



Early STOP Conditions

The MAX9777 recognizes a STOP condition at any point during the transmission except if a STOP condition occurs in the same high pulse as a START condition (Figure 5). This condition is not a legal I²C format; at least one clock pulse must separate any START and STOP condition.

REPEATED START Conditions

A REPEATED START (S_r) condition may indicate a change of data direction on the bus. Such a change occurs when a command word is required to initiate a read operation. S_r may also be used when the bus master is writing to several I²C devices and does not want to relinquish control of the bus. The MAX9777 serial interface supports continuous write operations with or without an S_r condition separating them. Continuous read operations require S_r conditions because of the change in direction of data flow.

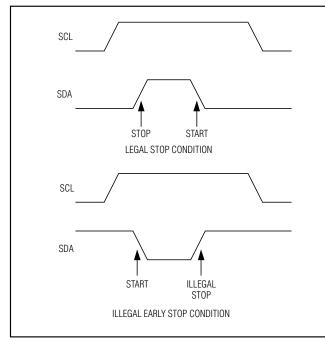


Figure 5. Early STOP Condition

Acknowledge Bit (ACK)

The acknowledge bit (ACK) is the ninth bit attached to any 8-bit data word. The receiving device always generates ACK. The MAX9777 generates an ACK when receiving an address or data by pulling SDA low during the night clock period. When transmitting data, the MAX9777 waits for the receiving device to generate an ACK. Monitoring ACK allows for detection of unsuccessful data transfers. An unsuccessful data transfer occurs if a receiving device is busy or if a system fault has occurred. In the event of an unsuccessful data transfer, the bus master should reattempt communication at a later time.

Slave Address

The bus master initiates communication with a slave device by issuing a START condition followed by a 7-bit slave address (Figure 6). When idle, the MAX9777 waits for a START condition followed by its slave address. The LSB of the address word is the Read/Write (R/W) bit. R/W indicates whether the master is writing to or reading from the MAX9777 (R/W = 0 selects the write condition, R/W = 1 selects the read condition). After receiving the proper address, the MAX9777 issues an ACK by pulling SDA low for one clock cycle.

The MAX9777 has a factory-/user-programmed address. Address bits A6–A2 are preset, while A0 and A1 is set by ADD. Connect ADD to either V_{DD} , GND, SCL, or SDA to change the last 2 bits of the slave address (Table 2).

			-					-
S	A6	A5	A4	A3	A2	A1	A0	R/W

Figure 6. Slave Address Byte Definition

Table 2. MAX9777 I²C Slave Addresses

ADD CONNECTION	I ² C ADDRESS
GND	100 1000
V _{DD}	100 1001
SDA	100 1010
SCL	100 1011

Write Data Format

aistors that a

There are three registers that configure the MAX9777: the MUTE register, SHDN register, and control register. In write data mode (R/W = 0), the register address and data byte follow the device address (Figure 7).

MUTE Register

The MUTE register (01hex) is a read/write register that sets the MUTE status of the device. Bit 3 (MUTEL) of the MUTE register controls the left channel; bit 4 (MUTER) controls the right channel. A logic-high mutes the respective channel; a logic-low brings the channel out of mute.

SHDN Register

The SHDN register (02hex) is a read/write register that controls the power-up state of the device. A logic-high

in bit 0 of the SHDN register shuts down the device; a logic-low turns on the device. A logic-high is required in bits 2 to 7 to reset all registers to their default settings.

Control Register

The control register (03hex) is a read/write register that determines the device configuration. Bit 1 (IN1/IN2) controls the input multiplexer, a logic-high selects input 1; a logic-low selects input 2. Bit 2 (HPS_D) controls the headphone sensing. A logic-low configures the device in automatic headphone detection mode. A logic-high disables the HPS input. Bit 3 (GAINA/B) controls the gain-select multiplexer. A logic-low selects GAINA. A logic-high selects GAINB. GAINA/B is ignored when HPS_D = 0. Bit 4 (SPKR/HP) selects the amplifier operating mode when HPS_D = 1. A logic-high selects speaker mode, and a logic-low selects headphone mode.

S	ADDRESS	WR	ACK	COMMAND	ACK	DAT	TA ACK	Р			
	7 BITS			8 BITS		8 BI	ITS	1			
S	I ² C SLAVE ADDRESS. SELECTS DEVICE. REGISTER ADDRESS. SELECTS REGISTER TO BE WRITTEN TO.						EGISTER DATA				
7 BITS I ² C SLAVE ADDRESS. SELECTS DEVICE.	ACK	COMMAND	ACK	S	ADDRESS	WR	ACK	DATA	Р		
	7 BITS			8 BITS			7 BITS			8 BITS	1
				REGISTER ADDRE SELECTS REGIS		ŀ	I ² C SLAVE ADD SELECTS DEV			DATA FROM SELECTED REGIS	

Figure 7. Write/Read Data Format Example

Table 3. MAX9777 MUTE Register Format

	ISTER DRESS		0000 0001
BIT	NAME	VALUE	DESCRIPTION
7	Х	Don't Care	_
6	Х	Don't Care	_
5	Х	Don't Care	—
4		0*	Unmute right channel
4	MUTER	1	Mute right channel
3	MUTEL	0*	Unmute left channel
3	WUTEL	1	Mute left channel
2	Х	Don't Care	_
1	Х	Don't Care	_
0	Х	Don't Care	
*Default	-4-4-		

*Default state.

Table 4. MAX9777 SHDN Register Format

REGIST	ER ADDRESS	0000 0010								
BIT	NAME	VALUE	DESCRIPTION							
7	RESET	0*	—							
	NESET	1	Reset device							
6	RESET	0*	_							
0	NESE I	1	Reset device							
5	RESET	0*	—							
5	NESET	1	Reset device							
4	RESET	0*	—							
4	NLOLI	1	Reset device							
3	RESET	0*	—							
5	NLOLI	1	Reset device							
2	RESET	0*	—							
2	NLOLI	1	Reset device							
1	Х	Don't Care								
0	SHDN	0*	Normal operation							
0	SIDN	1	Shutdown							

*Default state.



Table 5. MAX9777 Control Register Format

			•
REGIST	ER ADDRESS		0000 0011
BIT	NAME	VALUE	DESCRIPTION
7		Don't Care	—
6	Х	Don't Care	—
5	Х	Don't Care	—
		0*	Speaker mode selected
4	SPKR/HP	1	Headphone mode selected
0		0*	Gain-setting A selected
3	GAINA/B	1	Gain-setting B selected
		0*	Automatic headphone detection enabled
2	HPS_D	1	Automatic headphone detection disabled (HPS ignored)
-1		0*	Input 1 selected
1	IN1/IN2	1	Input 2 selected
0	Х	Don't Care	—

*Default

Table 6. MAX9777 Status Register Format

Read Data Format

In read mode (R/W = 1), the MAX9777 writes the contents of the selected register to the bus. The direction of the data flow reverses following the address acknowledge by the MAX9777. The master device reads the contents of all registers, including the read-only status register. Table 6 shows the status register format.

Interrupt Output (INT)

The MAX9777 includes an interrupt output (INT) that can indicate to a master device that an event has occurred. INT is triggered when the state of HPS changes. During normal operation, INT idles high. If a headphone is inserted/removed from the jack and that action is detected by HPS, INT pulls the line low. INT remains low until a read data operation is executed.

I²C Compatibility

The MAX9777 is compatible with existing I²C systems. SCL and SDA are high-impedance inputs; SDA has an open drain that pulls the data line low during the ninth clock pulse. The communication protocol supports the standard I²C 8-bit communications. The general call address is ignored. The MAX9777 slave addresses are compatible with the 7-bit I²C addressing protocol only.

REGI	STER ADDRESS		0000 0000
BIT	NAME	VALUE	DESCRIPTION
7	THRM	0	Device temperature below thermal limit
7		1	Device temperature exceeding thermal limit
6	AMPR-	0	OUTR- current below current limit
0	AMPR-	1	OUTR- current exceeding current limit
5		0	OUTR+ current below current limit
5	AMPR+	1	OUTR+ current exceeding current limit
4	AMPL-	0	OUTL- current below current limit
4	AMPL-	1	OUTL- current exceeding current limit
2		0	OUTL+ current below current limit
3	AMPL+	1	OUTL+ current exceeding current limit
0	LIDOTO	0	Device in speaker mode
2	HPSTS	1	Device in headphone mode
1	Х	Don't Care	_
0	Х	Don't Care	_

Applications Information

BTL Speaker Amplifiers

The MAX9777/MAX9778 feature speaker amplifiers designed to drive a load differentially, a configuration referred to as bridge-tied load (BTL). The BTL configuration (Figure 8) offers advantages over the singleended configuration, where one side of the load is connected to ground. Driving the load differentially doubles the output voltage compared to a singleended amplifier under similar conditions. Thus, the devices' differential gain is twice the closed-loop gain of the input amplifier. The effective gain is given by:

$$A_{VD} = 2 \times \frac{R_F}{R_{IN}}$$

Substituting 2 x VOUT(P-P) for VOUT(P-P) into the following equations yields four times the output power due to doubling of the output voltage:

$$V_{RMS} = \frac{V_{OUT(P-P)}}{2\sqrt{2}}$$
$$P_{OUT} = \frac{V_{RMS}^2}{R_L}$$

Since the differential outputs are biased at midsupply, there is no net DC voltage across the load. This eliminates the need for DC-blocking capacitors required for single-ended amplifiers. These capacitors can be large and expensive, consume board space, and degrade low-frequency performance.

When the MAX9777 is configured to automatically detect the presence of a headphone jack, the device defaults to gain setting A when the device is in speaker mode.

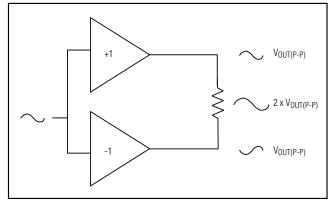


Figure 8. Bridge-Tied Load Configuration

Single-Ended Headphone Amplifier

The MAX9777/MAX9778 can be configured as singleended headphone amplifiers through software or by sensing the presence of a headphone plug (HPS). In headphone mode, the inverting output of the BTL amplifier is disabled, muting the speaker. The gain is 1/2 that of the device in speaker mode, and the output power is reduced by a factor of 4.

In headphone mode, the load must be capacitively coupled to the device, blocking the DC bias voltage from the load (see the Typical Application Circuits).

Power Dissipation and Heat Sinking

Under normal operating conditions, the MAX9777/ MAX9778 can dissipate a significant amount of power. The maximum power dissipation for each package is given in the Absolute Maximum Ratings section under Continuous Power Dissipation or can be calculated by the following equation:

$$P_{\text{DISSPKG}(\text{MAX})} = \frac{T_{\text{J}(\text{MAX})} - T_{\text{A}}}{\theta_{\text{JA}}}$$

where T_{J(MAX)} is +150°C, T_A is the ambient temperature, and θ_{JA} is the reciprocal of the derating factor in °C/W as specified in the Absolute Maximum Ratings section. For example, θ_{JA} of the TQFN package is +29°C/W.

The increase in power delivered by the BTL configuration directly results in an increase in internal power dissipation over the single-ended configuration. The maximum power dissipation for a given VDD and load is given by the following equation:

$$P_{\text{DISS}(\text{MAX})} = \frac{2V_{\text{DD}}^2}{\pi^2 R_{\text{L}}}$$

If the power dissipation for a given application exceeds the maximum allowed for a given package, either reduce V_{DD}, increase load impedance, decrease the ambient temperature, or add heatsinking to the device. Large output, supply, and ground PC board traces improve the maximum power dissipation in the package.

Thermal-overload protection limits total power dissipation in these devices. When the junction temperature exceeds +160°C, the thermal-protection circuitry disables the amplifier output stage. The amplifiers are enabled once the junction temperature cools by 15°C. This results in a pulsing output under continuous thermal-overload conditions as the device heats and cools.



Component Selection

Gain-Setting Resistors

External feedback components set the gain of the MAX9777/MAX9778. Resistor R_{IN} sets the gain of the input amplifier (A_{VIN}), and resistor R_F sets the gain of the second stage amplifier (A_{VOUT}):

$$A_{VIN} = -\left(\frac{10k\Omega}{R_{IN}}\right), \ A_{VOUT} = -\left(\frac{R_F}{10k\Omega}\right)$$

Combining A_{VIN} and A_{VOUT} , R_{IN} and R_{F} set the single-ended gain of the device as follows:

$$A_{V} = A_{VIN} \times A_{VOUT} = -\left(\frac{10k\Omega}{R_{IN}}\right) \times -\left(\frac{R_{F}}{10k\Omega}\right) = +\left(\frac{R_{F}}{R_{IN}}\right)$$

As shown, the two-stage amplifier architecture results in a noninverting gain configuration, preserving absolute phase through the MAX9777/MAX9778. The gain of the device in BTL mode is twice that of the single-ended mode. Choose R_{IN} between 10k Ω and 15k Ω and R_F between 15k Ω and 100k Ω .

Input Filter

The input capacitor (C_{IN}), in conjunction with \dot{R}_{IN} , forms a highpass filter that removes the DC bias from an incoming signal. The AC-coupling capacitor allows the amplifier to bias the signal to an optimum DC level. Assuming zero-source impedance, the -3dB point of the highpass filter is given by:

$$f_{-3dB} = \frac{1}{2\pi R_{IN}C_{IN}}$$

Choose R_{IN} according to the *Gain-Setting Resistors* section. Choose the C_{IN} such that f_{-3dB} is well below the lowest frequency of interest. Setting f_{-3dB} too high affects the amplifier's low-frequency response. Use capacitors whose dielectrics have low-voltage coefficients, such as tantalum or aluminum electrolytic. Capacitors with high-voltage coefficients, such as ceramics, may result in an increased distortion at low frequencies.

Other considerations when designing the input filter include the constraints of the overall system, the actual frequency band of interest, and click-andpop suppression.

Output-Coupling Capacitor

The MAX9777/MAX9778 require output-coupling capacitors to operate in single-ended (headphone) mode. The output-coupling capacitor blocks the DC component of the amplifier output, preventing DC current from flowing to the load. The output capacitor and

the load impedance form a highpass filter with a -3dB point determined by:

$$f_{-3dB} = \frac{1}{2\pi R_L C_{OUT}}$$

As with the input capacitor, choose C_{OUT} such that f_{-3dB} is well below the lowest frequency of interest. Setting f_{-3dB} too high affects the amplifier's low-frequency response.

Load impedance is a concern when choosing C_{OUT}. Load impedance can vary, changing the -3dB point of the output filter. A lower impedance increases the corner frequency, degrading low-frequency response. Select C_{OUT} such that the worst-case load/C_{OUT} combination yields an adequate response. Select capacitors with low ESR to minimize resistive losses and optimize power transfer to the load.

If layout constraints require a physically smaller outputcoupling capacitor, decrease the value of C_{OUT} and add series resistance to the output of the MAX9777/MAX9778 (see Figure 9). With the added series resistance at the output, the cutoff frequency of the highpass filter is:

$$f_{-3dB} = \frac{1}{2\pi (R_L + R_{SERIES})C_{OUT}}$$

Since the cutoff frequency of the output highpass filter is inversely proportional to the product of the total load resistance seen by the outputs (R_L + R_{SERIES}) and C_{OUT} , increase the total resistance seen by the MAX9777/MAX9778 outputs by the same amount C_{OUT} is decreased to maintain low-frequency performance. Since the added series resistance forms a voltagedivider with the headphone speaker resistance for frequencies within the passband of the highpass filter, there is a loss in voltage gain. To compensate for this loss, increase the voltage gain setting by an amount equal to the attenuation due to the added series resistance. Use the following equation to approximate the required voltage gain compensation:

$$A_{V_{COMP}} = 20 \log \left(\frac{R_{L} + R_{SERIES}}{R_{L}} \right)$$

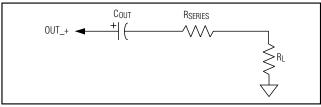


Figure 9. Reducing COUT by Adding RSERIES

MAX9777/MAX9778

BIAS Capacitor

BIAS is the output of the internally generated 2.5VDC bias voltage. The BIAS bypass capacitor, CBIAS, improves PSRR and THD+N by reducing power supply and other noise sources at the common-mode bias node, and also generates the clickless/popless, start-up/shutdown DC bias waveforms for the speaker amplifiers. Bypass BIAS with a 1 μ F capacitor to GND.

Supply Bypassing

Proper power-supply bypassing ensures low-noise, low-distortion performance. Place a 0.1μ F ceramic capacitor from V_{DD} to GND. Add additional bulk capacitance as required by the application, typically 100 μ F. Bypass PV_{DD} with a 100 μ F capacitor to GND. Locate bypass capacitors as close to the device as possible.

Gain Select

The MAX9777/MAX9778 feature multiple gain settings on each channel, making available different gain and feedback configurations. The gain-setting resistor (R_F) is connected between the amplifier output (OUT_+) and the gain set point (GAIN_). An internal multiplexer switches between the different feedback resistors depending on the status of the gain control input. The stereo MAX9777/MAX9778 feature two gain options per channel. See Tables 1a and 1b for the gain-setting options.

Bass Boost Circuit

Headphones typically have a poor low-frequency response due to speaker and enclosure size limitations. A bass boost circuit compensates the poor low-frequency response (Figure 10). At low frequencies, the capacitor C_F is an open circuit, and the effective impedance in the feedback loop ($R_{F(EFF)}$) is $R_{F(EFF)} = R_{F1}$.

At the frequency:



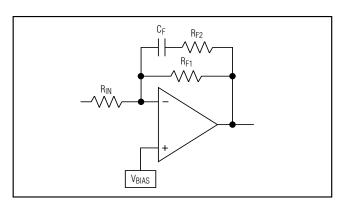


Figure 10. Bass Boost Circuit

where the impedance, C_F , begins to decrease, and at high frequencies, the C_F is a short circuit. Here the impedance of the feedback loop is:

$$R_{F(EFF)} = \frac{R_{F1} \times R_{F2}}{R_{F1} + R_{F2}}$$

Assuming $R_{F1} = R_{F2}$, then $R_{F(EFF)}$ at low frequencies is twice that of $R_{F(EFF)}$ at high frequencies (Figure 11). Thus, the amplifier has more gain at lower frequencies, boosting the system's bass response. Set the gain rolloff frequency based upon the response of the speaker and enclosure.

To minimize distortion at low frequencies, use capacitors with low-voltage coefficient dielectrics when selecting CF. Film or COG dielectric capacitors are good choices for CF. Capacitors with high-voltage coefficients, such as ceramics (non-COG dielectrics), can result in increased distortion at low frequencies.

Layout and Grounding

Good PC board layout is essential for optimizing performance. Use large traces for the power-supply inputs and amplifier outputs to minimize losses due to parasitic trace resistance, as well as route heat away from the device. Good grounding improves audio performance, minimizes crosstalk between channels, and prevents any digital switching noise from coupling into the audio signal. If digital signal lines must cross over or under audio signal lines, ensure that they cross perpendicular to each other.

The MAX9777/MAX9778 TQFN package features an exposed thermal pad. This pad lowers the package's thermal resistance by providing a direct heat conduction path from the die to the PC board. Connect the pad to signal ground (0V) by using a large pad or multiple vias to the ground plane.

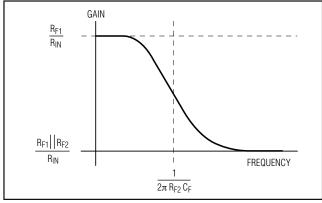
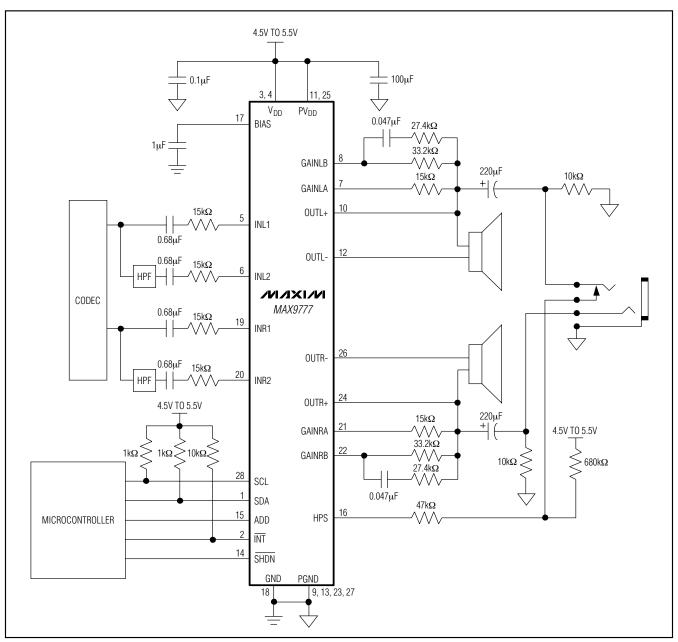
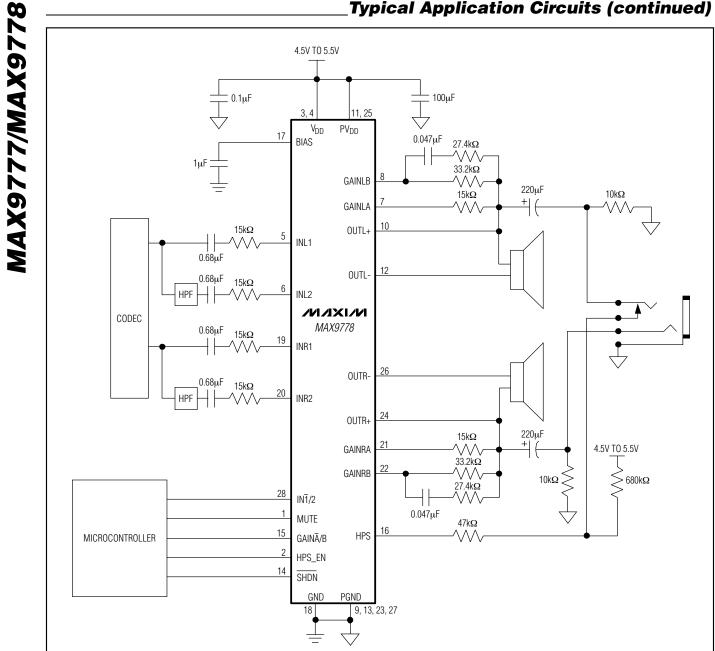


Figure 11. Bass Boost Response



Typical Application Circuits

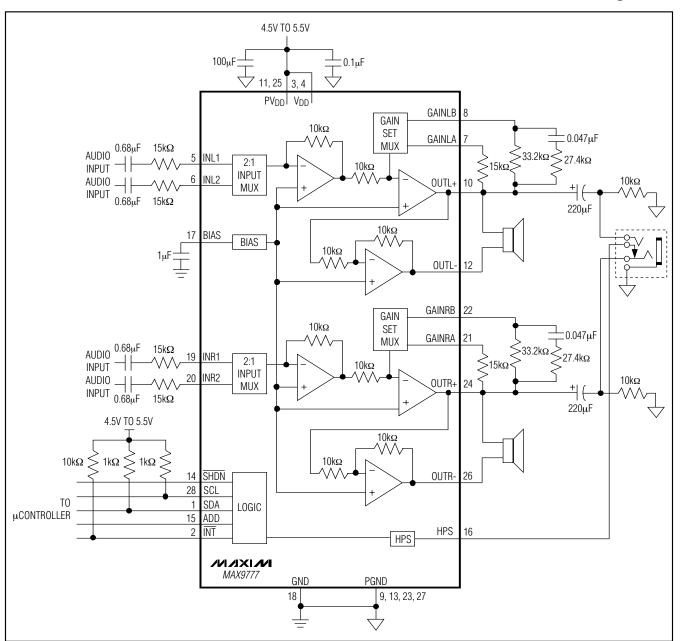


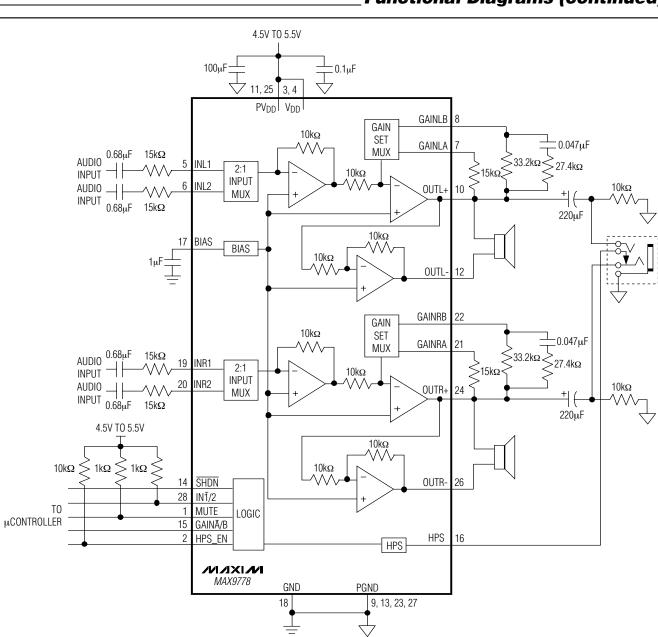


Typical Application Circuits (continued)

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Functional Diagrams



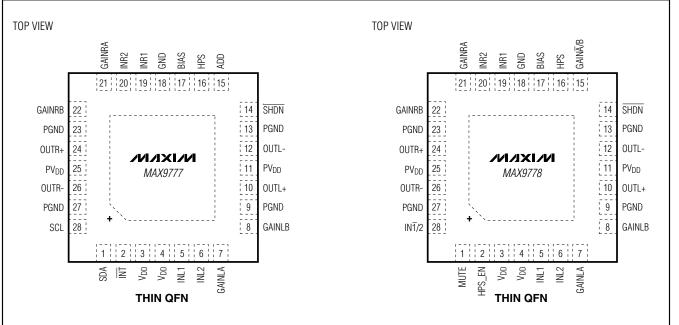


Functional Diagrams (continued)



MAX9777/MAX9778

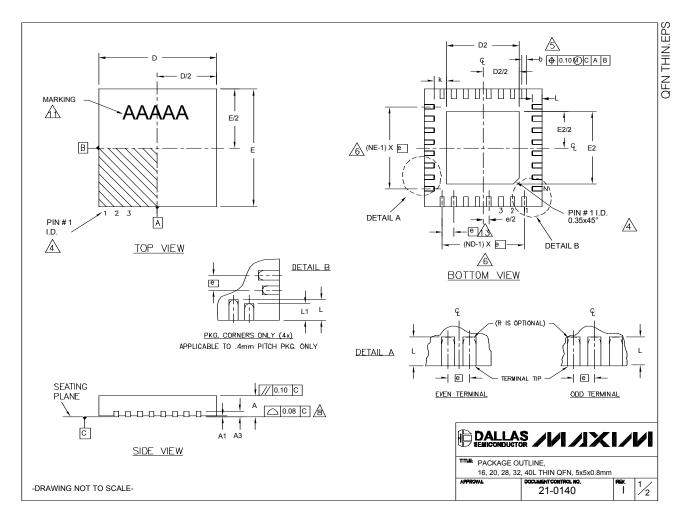
_Pin Configurations



MAX9777/MAX9778

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)





Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)

			С	OMMC	DN DI	IMEN	SION	5										EXPOSED PAD VARIATIONS									
PKG.	1	6L 5x	:5	20)L 5×	(5	2	8L 5x	5	3	32L 5x	5	4	40L 5×	‹ 5	1	PKG.		D2			E2			DOWN		
SYMBOL	MIN.	NOM.	MAX.	MIN. I	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		CODES	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	±0.15	BONDS		
A	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80		T1655-2	3.00	3.10	3.20	3.00	3.10	3.20	**	YES	3	
A1	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05		T1655-3	3.00	3.10	3.20	3.00	3.10	3.20	**	NO	,	
A3	0	20 RE	F.	0.2	20 RE	F.	0.	20 RE	F.	0.	20 RE	F.	0	20 RE	F.		T1655N-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO	,	
b				0.25													T2055-3	3.00	3.10	3.20	3.00	3.10	3.20	**	YES	3	
D				4.90													T2055-4	3.00	3.10	3.20	3.00	3.10	3.20	**	NO	,	
E	_			4.90												-	T2055-5	3.15	3.25	3.35	3.15	3.25	3.35	0.40	YES	3	
e	-	.80 B		0.25	65 BS	SC.		.50 BS	-	0.25	.50 BS	<u>.</u>		.40 BS		1	T2855-3	3.15	3.25	3.35	3.15	3.25	3.35	**	YES	3	
k L	0.25	- 0.40		0.25	-	-	0.25	-				-		0.35			T2855-4	2.60	2.70	2.80	2.60	2.70	2.80	**	YES	3	
 	0.30	0.40	0.50	0.45	-	0.05	0.40	- 0.55	0.03	0.30	0.40	- 0.50	0.40	0.50		1	T2855-5	2.60		2.80			2.80	**	NO	,	
N	-	- 16	-	- 1	- 20	-	-	- 28	-	-	32	-	0.30	40	0.50		T2855-6	3.15	3.25	3.35	3.15	3.25	3.35	**	NO	,	
ND		4			5			7			8			10		1	T2855-7	2.60	2.70	2.80	2.60	2.70	2.80	**	YES	3	
NE		4			5			7			8			10		1	T2855-8	3.15	3.25	3.35	3.15	3.25	3.35	0.40	YES	3	
JEDEC		WHH	В	V	VHHC	2	V	VHHD	·1	V	VHHD	-2					T2855N-1	3.15	3.25	3.35	3.15	3.25	3.35	**	NO	,	
																	T3255-3	3.00	3.10	3.20	3 .00	3.10	3.20	**	YES	3	
OTES:																	T3255-4	3.00	3.10	3.20	3 .00	3.10	3.20	**	NO)	
1. DIM	IENSI	ONING	G & TC	DLERA	NCIN	G CO	NFOF	км то	ASM	E Y14	.5M-1	994.					T3255-5	3.00		3.20			3.20	**	YES	_	
2. ALL	. DIME	NSIO	NS AF	RE IN M	AILLIN	ИЕТЕ	RS. A	NGLES	ARE	E IN D	EGRE	ES.					T3255N-1	3.00		3.20		3.10	3.20	**	NO		
3. N IS	S THE	ΤΟΤΑ		MBER (OF TE	ERMI	NALS.										T4055-1	3.20	3.30	3.40	3.20	3.30	3.40	**	YES	3	
OPT IDE	NFOR TIONA NTIFI 1ENSI 5 mm	M TO IL, BU ER MA ON b A AND 0	JESD T MUS AY BE APPLI 0.30 m	95-1 S ST BE I EITHE ES TO m FRO	PP-0 LOCA R A M MET.	12. D ATED MOLD ALLIZ RMIN	Detail With Or M Ed Te Ial Ti	LS OF IN THE IARKE ERMIN P.	TERN ZON D FE AL AI	VINAL NE INE ATUR ND IS	. #1 ID DICATI RE. MEAS	ENTI ED. T SURE	FIER J HE TI D BE1	ARE ERMIN IWEEI	IAL # N		ίLΥ.										
7. DEF	POPU	LATIO	N IS F	POSSIE	BLE I	N A S	YMME	TRICA	L FA	SHIO	N.																
<u>787</u> COI	PLAN	ARITY	APPL	IES TO) THE	EEXF	OSED	HEAT	SIN	K SLL	JG AS	WEL	L AS '	THE TI	ERMI	NALS											
9. DR/ T28	AWIN 355-37				JEDE	EC MO	D220,	EXCE	PT EX	XPOS	ED PA	D DI	MENS	ION F	OR			Г									
10. WA	RPAG	E SH	ALL N	OT EX	CEEC	0.10	mm.											l	ΠA	ΔΙΙ	ΔS		41 4				
11. MA	RKING	S IS FO	OR PA	CKAG	E OR	IENT	ATION	I REFE	REN	ICE OI	NLY.							l	17 SEI	COND	UCTOR .	/ V		IX		1	
12. NUM	MBER	OF L	EADS	SHOW	/N AF	RE FO	R REF	EREN	CEC	ONLY.								ŀ	TITLE: D	ACKAC	E OUT						
13 LEA	AD CE	NTER	LINES	5 TO BE	EAT	TRUE	POS	TION	AS D	EFINE	ED BY	BASI	C DIN	IENSI	ON "e	", ±0.0)5.						N QFN.	5x5x0.8	mm		
			CALE															F	APPROVAL	-,, -		SUMENT OF	NTROL NO.)140		REV.	2	

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